NSN 5962-01-386-3131

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.04 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Landing gear e/i fscm 80477
Features Provided:
Bipolar and electrostatic sensitive and programmed
Inclosure Configuration:
Dual-in-line
Case Outline Source And Designator:
D-3 mil-m-38510
Product Name:
8k x 8 bipolar prom
Voltage Rating And Type Per Characteristic:
-0.3 volts absolute input and 7.0 volts absolute input
Time Rating Per Chacteristic:
100.00 nanoseconds af output megawatts
Memory Device Type:
Prom
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-88
standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:
A458a0